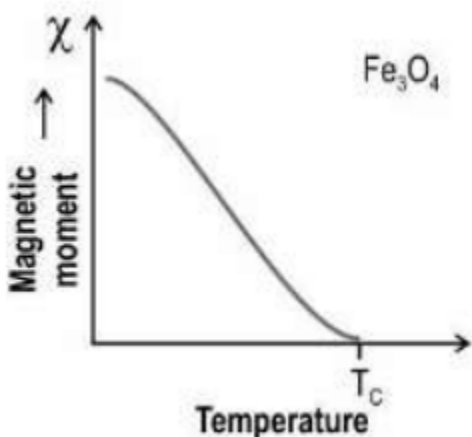


CBSE 12 Chemistry

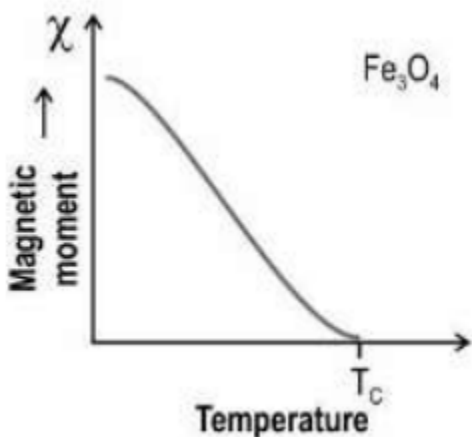
Chapter - The Solid State

Competency-Based Questions 2024-25

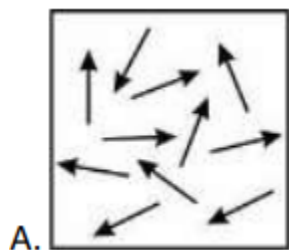
Q.1 The below graph shows the variation of the magnetic property of magnetite (Fe_3O_4) with respect to temperature.



Based on this graph, which of the following represents the alignment of the magnetic moment of Fe_3O_4 at $T > T_c$?



Answer.



Q.2 Given below are two statements labeled as Assertion (A) and Reason (R).

Assertion (A): Frenkel defect is shown by compounds having a low r^+/r^- ratio and low dielectric constant.

Reason (R): Frenkel defect maintains the neutrality of a crystal.

Select the most appropriate answer from the options given below:

- A. Both A and R are true and R is the correct explanation of A.
- B. Both A and R are true but R is not the correct explanation of A.
- C. A is true but R is false.
- D. A is false but R is true.

Answer. D. A is false but R is true

Q.3 Which combination of the characteristics of element X, a metal, and Y, a non-metal, is most likely to lead to ionic bonding?

	Element X	Element Y
A	Low ionization energy	High electronegativity value
B	Low ionization energy	Low electronegativity value
C	High ionization energy	High electronegativity value
D	High ionization energy	Low electronegativity value

Answer. A. A

Q.4 Which of the following combinations is INCORRECT?

	Name of the Compound	Type of semiconductor
A	GeP	n-type
B	SbSi ₄	n-type
C	GeAs	p-type
D	AlSi ₄	p-type

Answer. C. C

Q.5 Which of the following statements is/are true?

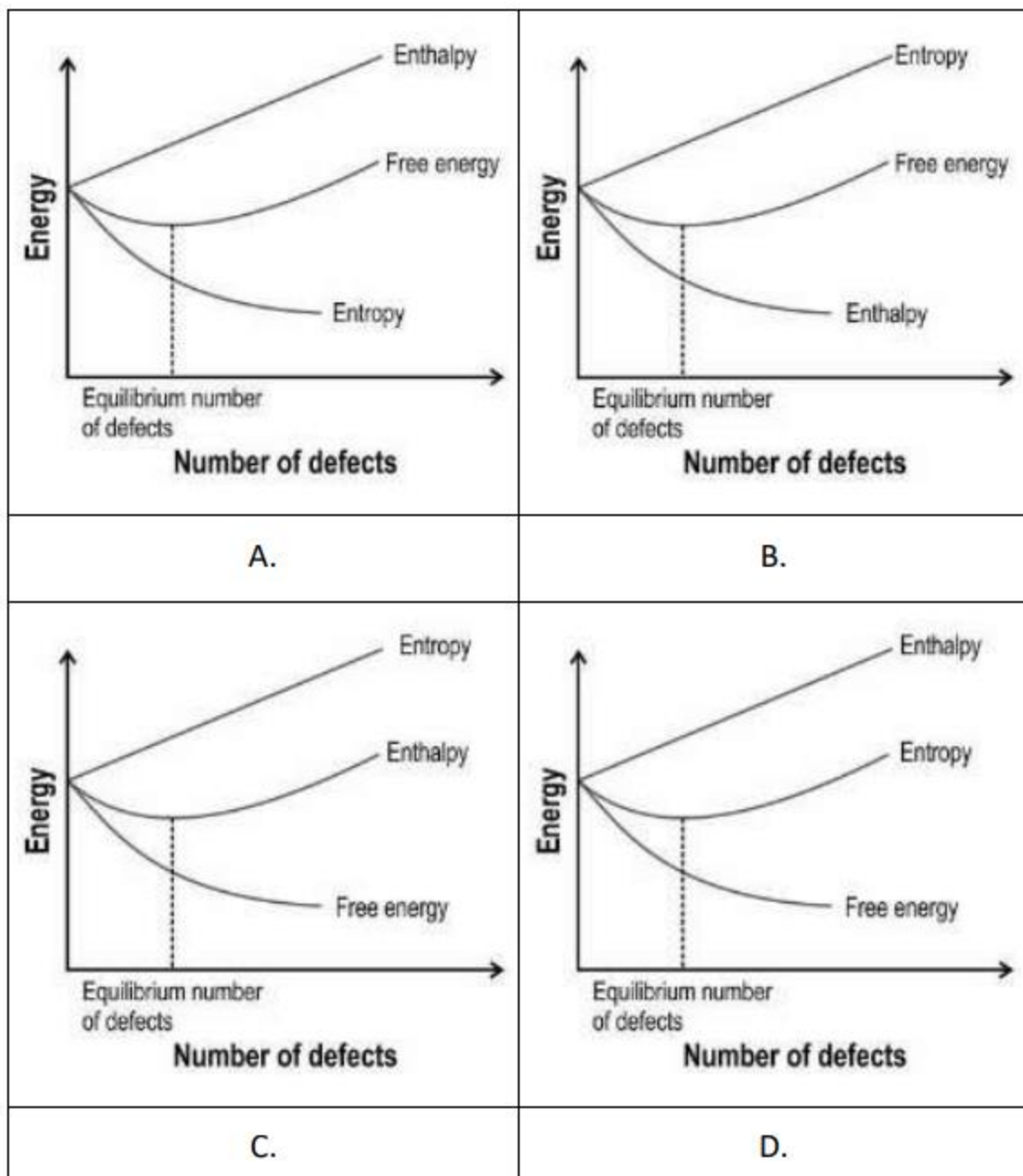
- (i) A non-stoichiometric compound Fe_{0.94}O is formed when 18% of Fe²⁺ ions are replaced by Fe³⁺ ions.
- (ii) The conductivity of both intrinsic and extrinsic semiconductors is directly proportional to temperature.
- (iii) The BCC structure is the densest crystal structure.

- A. i and iii
- B. ii and iii
- C. only i
- D. i and ii

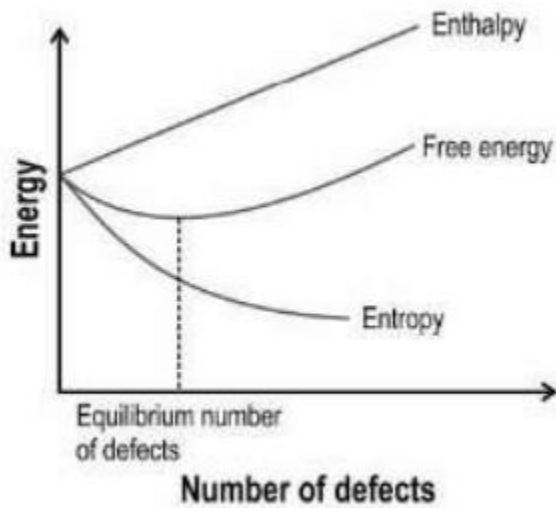
Answer. C. only i

Q.6 Which of the following graphs correctly represents the enthalpy, free energy, and entropy during the formation of Schottky defects in solids?

(Hint: The overall change in free energy is given by $\Delta G = \Delta H - T\Delta S$)

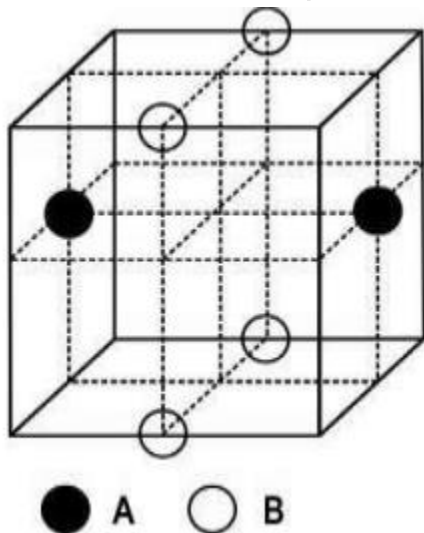


Answer.



A.

Q.7 A compound is formed by two ions A and B in a cubic unit cell. The radius of A⁺ is smaller than that of B⁻. (as shown below)



Which of the following statement is/are correct?

- (i) The radius ratio, r_+/r_- is 0.414.
- (ii) The cations and anions have different coordination geometry.
- (iii) The ratio of A-B bond length to unit cell edge length is 0.866.
- (iv) The formula of the compound is AB.

A. i and iii

B. iii and iv

- C. ii and iv
- D. All of them

Answer. B. iii and iv

Q.8 Read the statements below and answer the question based on them:

- Graphite conducts electricity and is used as a lubricant.
- Diamond is hard and does not conduct electricity.

Explain these statements on the basis of the structure and bonding present in these two solids.

Answer. Graphite:

- Each carbon atom is covalently bonded to three other carbon atoms forming flat, hexagonal rings which are arranged in layers [0.5]
- C has sp^2 hybridization. Due to this the fourth valence electron is delocalized and is free to move. Free moving electrons make it a good conductor. [0.5]
- Graphite is used as a lubricant because the layers of graphite are held together by weak intermolecular/ 'Van der Waals' forces and hence these layers can slide over each other [1 mark]

Diamond:

- Each carbon atom is covalently bonded to 4 other carbon atoms, forming a tetrahedral structure around C. C has sp^3 hybridization [1 mark]
- The strong covalent bonds and tetrahedral structure and absence of delocalized electrons make diamond hard and an electrical insulator. [1 mark]

Q.9 KCl crystallizes in the same type of lattice as NaCl. If $r_{Na^+}/r_{Cl^-} = 0.5$ and $r_{Na^+}/r_{K^+} = 0.7$.

What is the ratio of the side of the NaCl unit cell to that of the KCl unit cell?

Answer. Calculating ratio of the side of NaCl to that of KCl:

- NaCl crystallizes in fcc unit such that $r_{Na^+} + r_{Cl^-} = a/2$ (assuming a is side length of an unit cell for NaCl)[0.5 marks]
- Given that $r_{Na^+} / r_{Cl^-} = 0.5$
and $r_{Na^+}/r_{K^+} = 0.7$, thus

$$(r_{Na^+} + r_{Cl^-})/r_{Cl^-} = 1.5 \text{ and}$$

$$r_{K^+}/r_{Cl^-} = 0.5/0.7 \text{ [0.5 marks]}$$

- Using the above equations:

$$(r_{K^+} + r_{Cl^-})/(r_{Na^+} + r_{Cl^-}) = (1.2/0.7) \times (1/1.5)$$

$$\therefore a_{NaCl} : a_{KCl} = 1:1.143 \text{ [1 mark]}$$

Q.10 Explain why crystalline solids are generally MORE DEFECTIVE at high temperatures.
(Hint: Use the Gibbs energy equation)

Answer. - As per the Gibbs-Helmholtz equation:

$$\Delta G = \Delta H - T\Delta S;$$

To create defects, the enthalpy of formation must be provided. [1 mark]

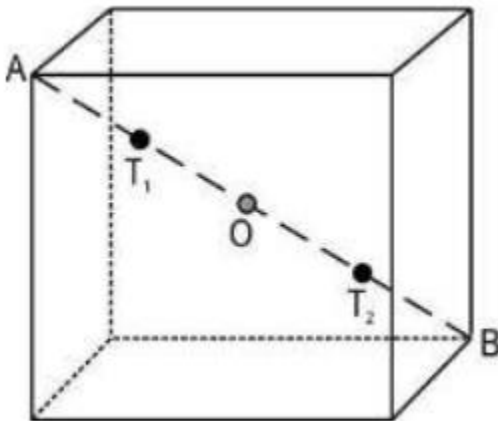
- A large positive increase in entropy will be associated with the defect.

- At high temperatures, it is more likely that the term $T\Delta S > \Delta H$, and thus $\Delta G < 0$ and defects may form at thermodynamic equilibrium. [1 mark]

Q.11 In an FCC lattice, with the help of a diagram, show that the minimum distance between an octahedral void and a tetrahedral void is $(\sqrt{3}/4)a$.

(Note: a is the side length of the unit cell)

Answer. Calculating the shortest distance between an octahedral void and a tetrahedral void in FCC solid: - Draw the diagram of one-unit cell showing the position of the octahedral void, and tetrahedral void as below: [1 mark]



- In the above figure, AB is the diagonal of the cube, T₁ and T₂ are tetrahedral voids, and O is the octahedral void at the centre of the cube. [0.5 mark]

- In FCC, tetrahedral voids are located at $1/4$ th distance from the corner along the diagonal. So, $AT_1 = AB/4$ - Since $AB = \sqrt{3}a$; $AT_1 = \sqrt{3}a/4$ [1 mark]

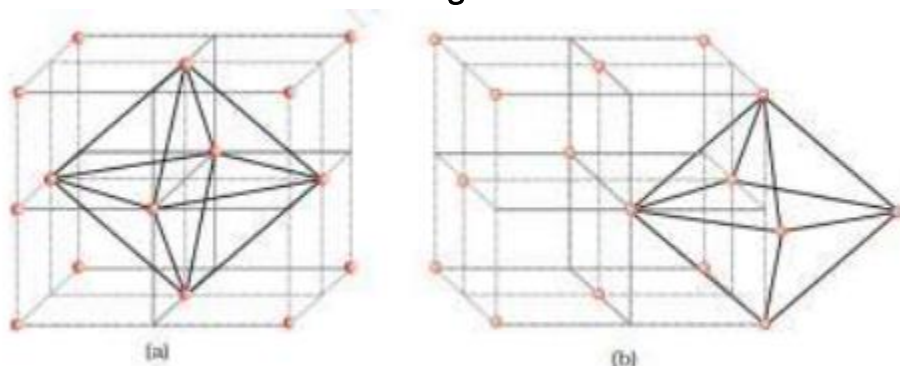
- Since the octahedral void is at the centre of the cube/diagonal. So, $AO = AB/2$

$$\therefore AO = \sqrt{3}a/2 \text{ [0.5 mark]}$$

- Now the distance between an octahedral void and a tetrahedral void = $AO - AT_1$

$$= \sqrt{3}a/2 - \sqrt{3}a/4 = \sqrt{3}a/4 \text{ [1 mark]}$$

Q.12 The diagram below shows the location of octahedral void per unit cell at the body center and at the center of one edge of the unit.



If the distance between the two nearest octahedral voids is $\sqrt{2}p$ cm, where p is any positive number.

(i) What is the minimum distance between the two tetrahedral voids in the same unit cell?

(ii) What is the maximum distance between the two tetrahedral voids in the same unit cell?

Answer. (i) minimum distance between the two tetrahedral voids

- minimum distance between the two octahedral voids = $a/\sqrt{2}$; where a is the side of the unit cell.

- $a/\sqrt{2} = \sqrt{2}p$; p is a positive number

$$\therefore a = 2p \text{ [1 Mark]}$$

So, the minimum distance between the two tetrahedral voids = $a/2 = p$ [1 mark]

(ii) the maximum distance between the two tetrahedral voids

- the maximum distance between the two tetrahedral voids = $\sqrt{3}a/2$; where a is the side length of unit cell

- so maximum distance = $\sqrt{3}p$ [1 mark]

Q.13 In a crystal, there are N possible cation and anion sites. If there are n_c cation vacancies and n_a anion vacancies in the same crystal, then what is the number of ways in which one can distribute:

(i) Cation vacancies

(ii) Anion vacancies

(iii) Total number of ways of distributing these defects

Answer. (i) No. of ways one can distribute cation vacancies:

- Probability theory shows that the no. of ways of distributing n defects over N sites = $N!/(N-n)!n!$

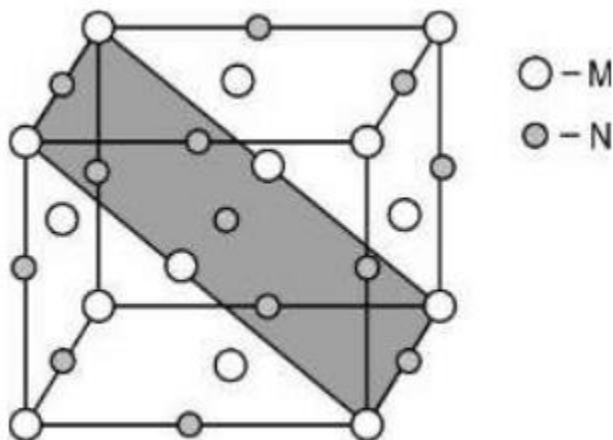
$\therefore$ No. of ways one can distribute cation vacancies = $N!/(N-n_c)!n_c!$ [0.5 mark]

(ii) Similarly, No. of ways one can distribute anion vacancies = $N!/(N-n_a)!n_a!$ [0.5 mark]

(iii) Total number of ways of distributing these defects = $N!/(N-n_c)!n_c! \times N!/(N-n_a)!n_a!$ [1 mark]

Q.14 A compound is formed by two elements M and N. The element M forms fcc lattice and N occupies all the octahedral voids.

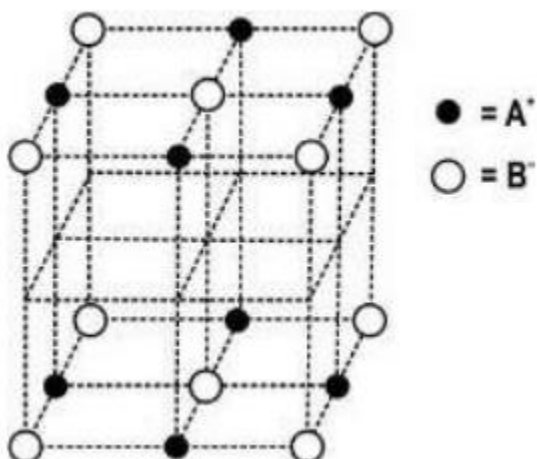
If all the atoms along the 011 plane (as shown below in grey) are missing, then derive the formula of the compound?



Answer. Finding the formula of the compound:

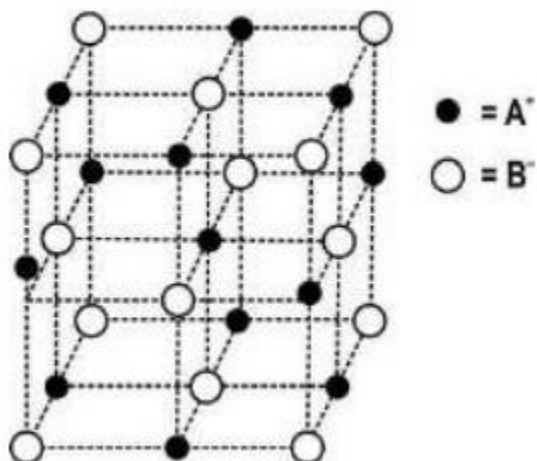
- In the new arrangement the no of atoms of M = $(\frac{1}{8} \times 8 + \frac{1}{2} \times 6) - (\frac{1}{8} \times 4 + \frac{1}{2} \times 2) = \frac{5}{2}$ [1 mark]
- the no. of atoms of N = $(\frac{1}{4} \times 12 + 1) - (\frac{1}{4} \times 2 + 1) = \frac{5}{2}$ [1 mark]
- So the new formula = MN [1 mark for correct answer]

Q.15 The diagram below shows a part of the structure of a crystal with some ions missing.



- Complete the diagram by placing cation A and anion B at appropriate sites.
- Identify the formula of this crystal.

Answer. (i) Diagram



(ii) Formula:

- No. of atoms A = $(\frac{1}{4} \times 12 + 1) = 4$ [0.5 mark]

- No. of atoms B = $\frac{1}{8} \times 8 + \frac{1}{2} \times 6 = 4$ [0.5 mark]

- Formula = AB [1 mark]